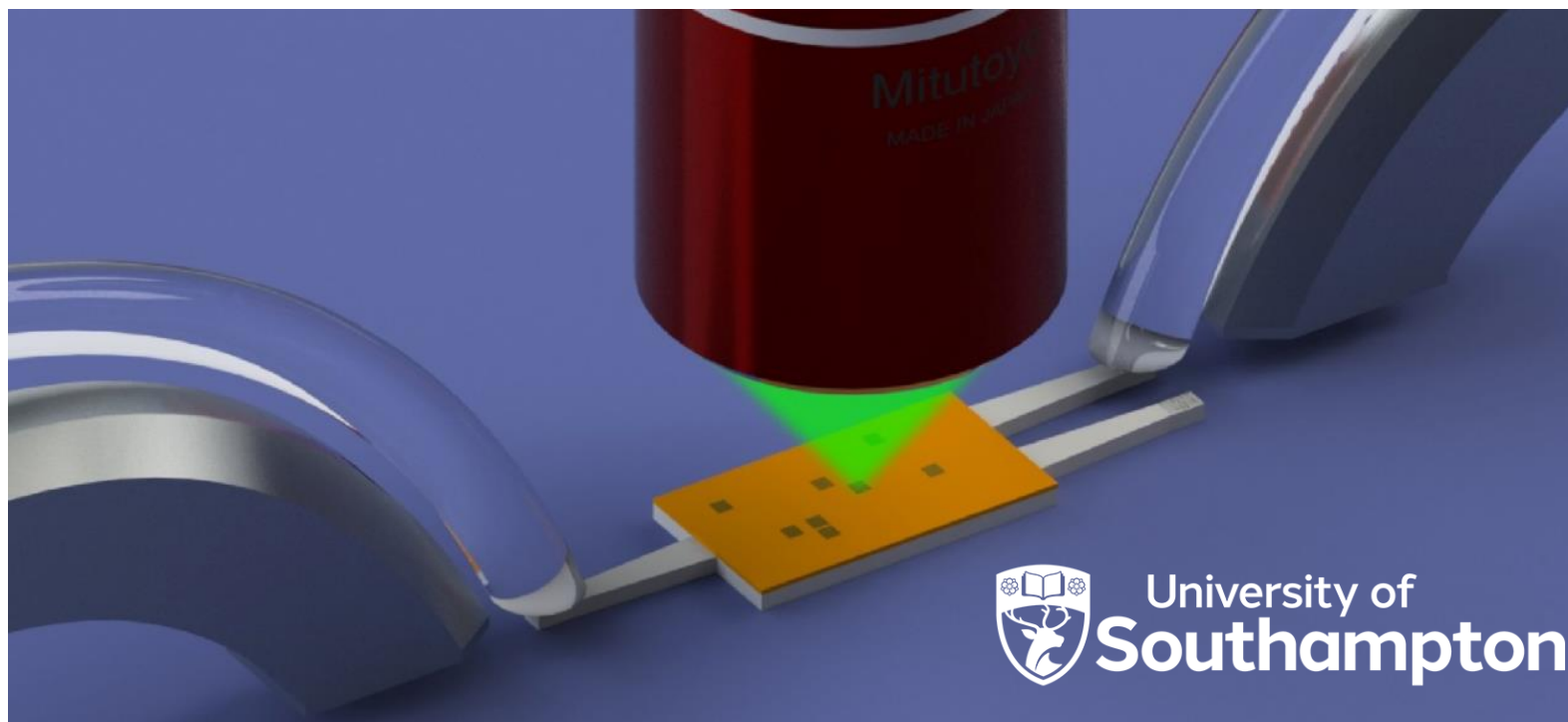


~~Thermochromics~~ and Phase-change technologies for sustainable photonics

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UK Metamaterials Network, 14 June 2023

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Callum Wheeler



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Matthew Delaney



Kees de Groot



Kai Sun



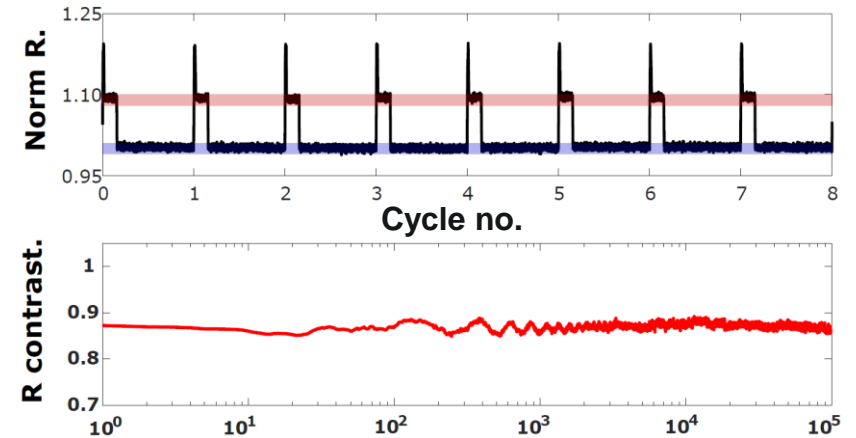
Ioannis Zeimpekis

Integrated Nanophotonics group

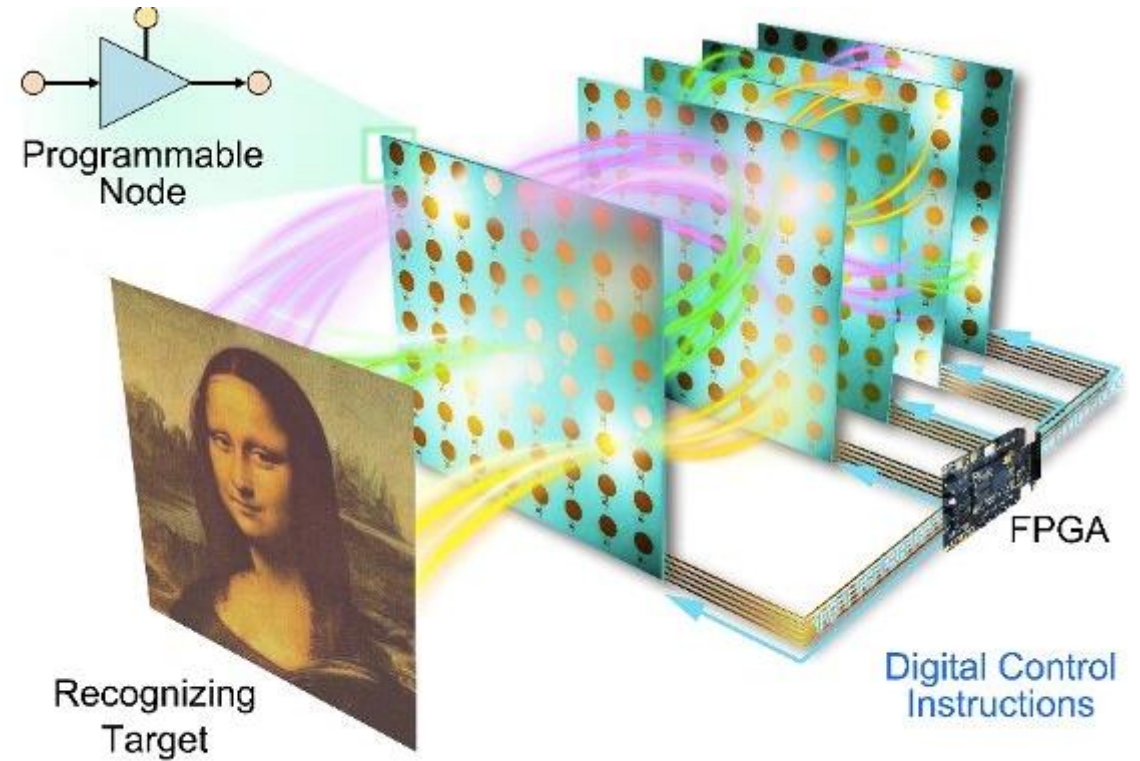
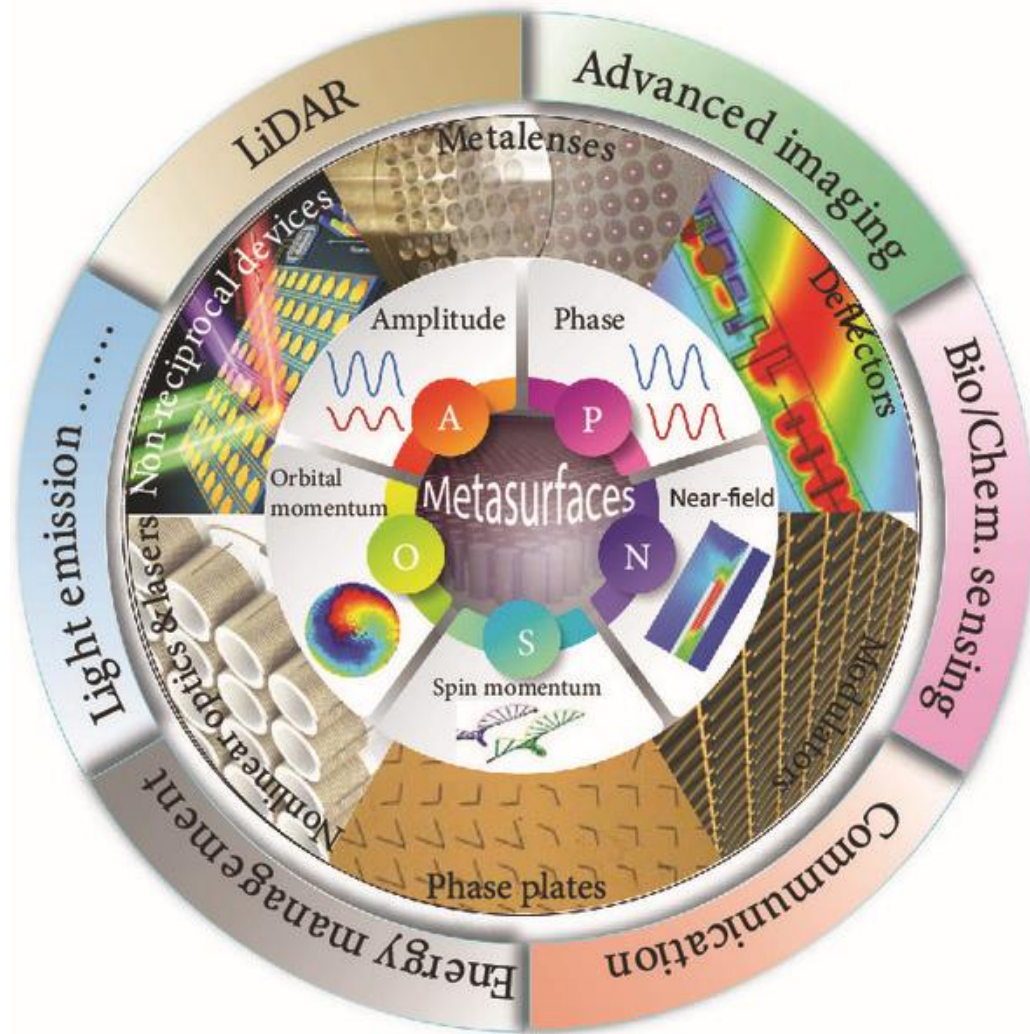


Outline

- New low-loss phase change materials for photonics
- Optical switching of Sb_2Se_3 films for metasurface applications



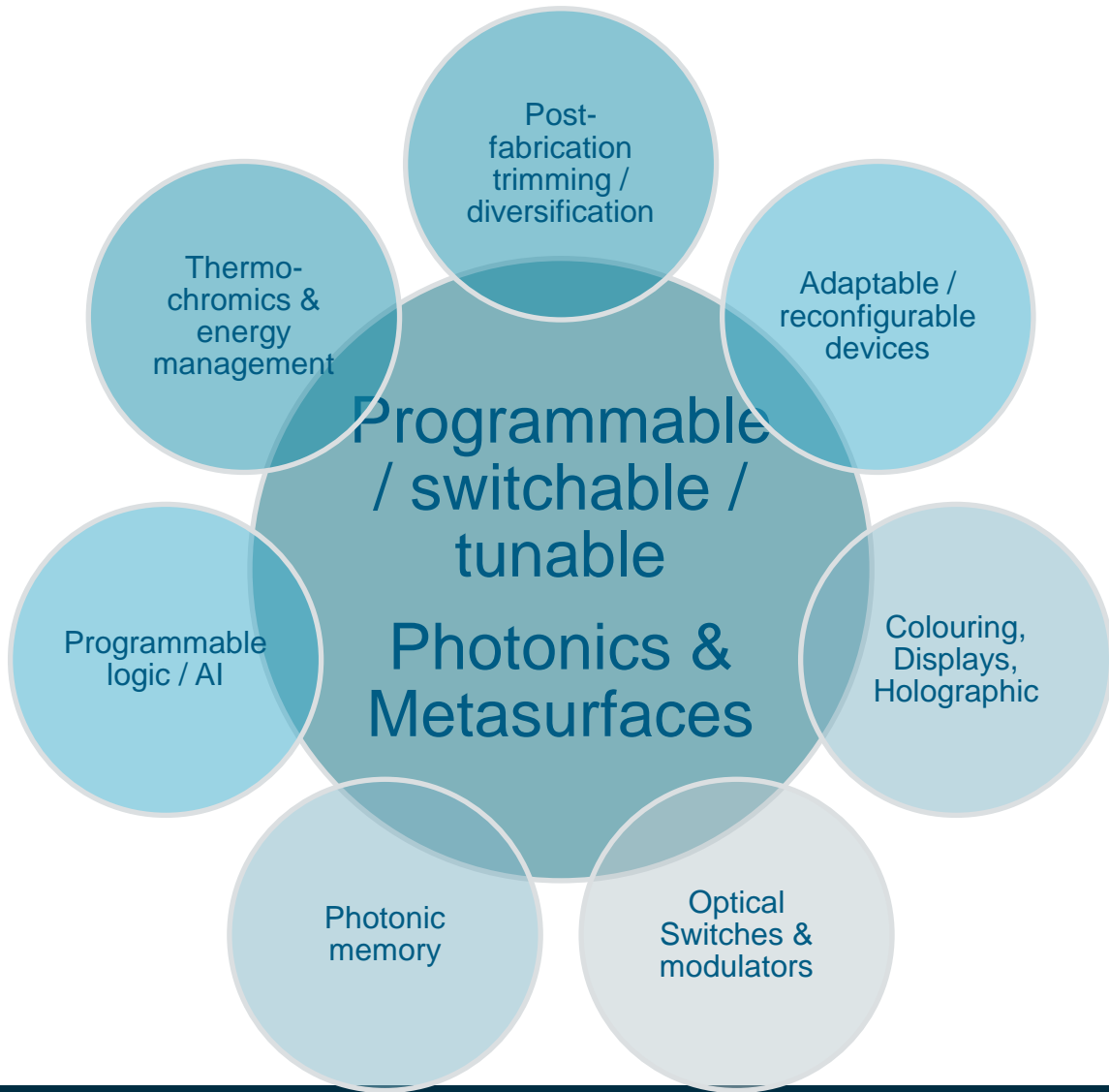
Programmable / switchable photonics: application perspective



[DOI: 10.1038/s41928-022-00719-9](https://doi.org/10.1038/s41928-022-00719-9)

DOI: [10.34133/2022/9765089](https://doi.org/10.34133/2022/9765089)

Programmable / switchable photonics: application perspective



Optical programming

- Direct (laser) writing
- Offline (in factory), set & forget

Electrical programming

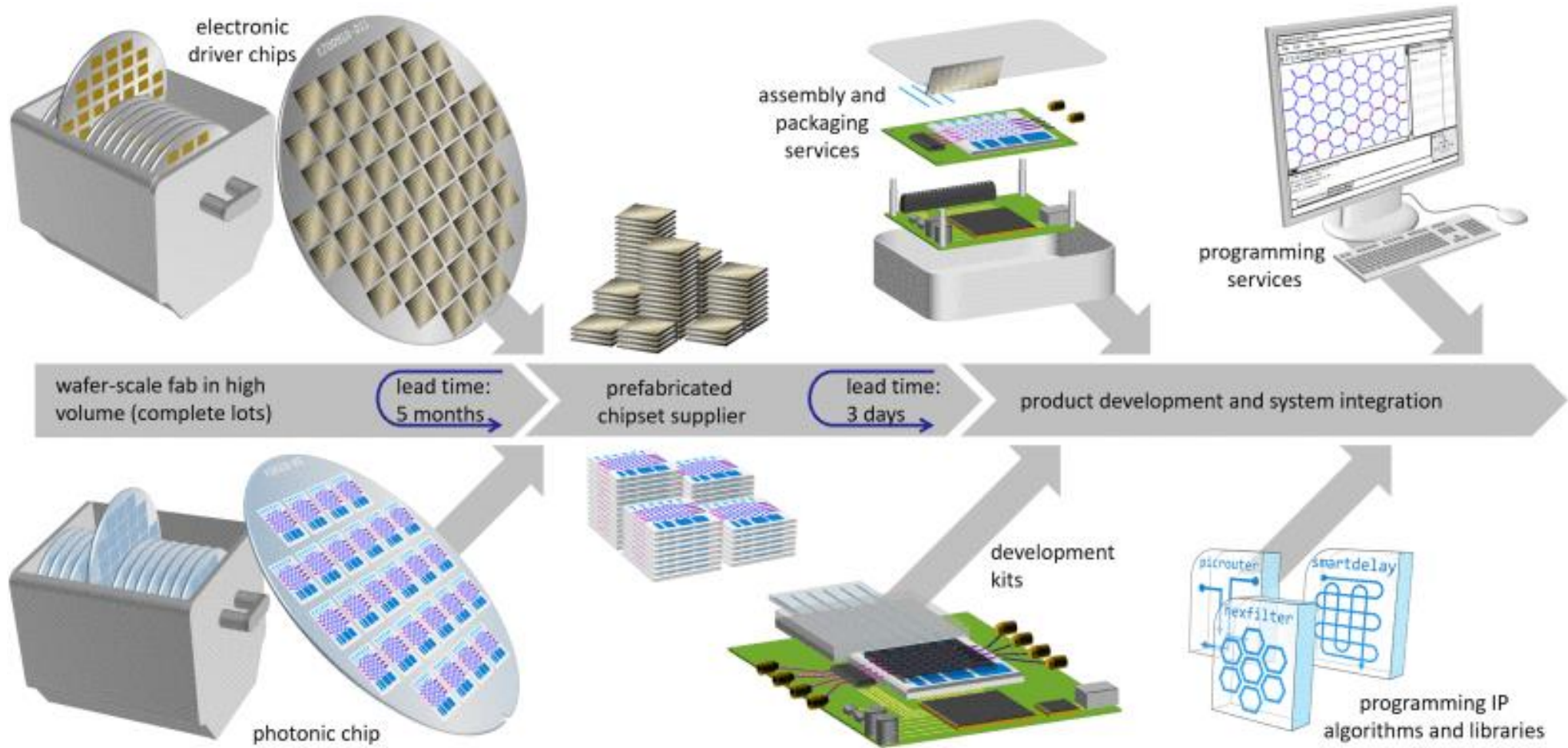
- Device-level actuation
- Requires electrical contacts, interface, regulation

Thermally responsive

- Through local heating or environment
- Passive regulation

...

Programmable photonics: supply chain benefits

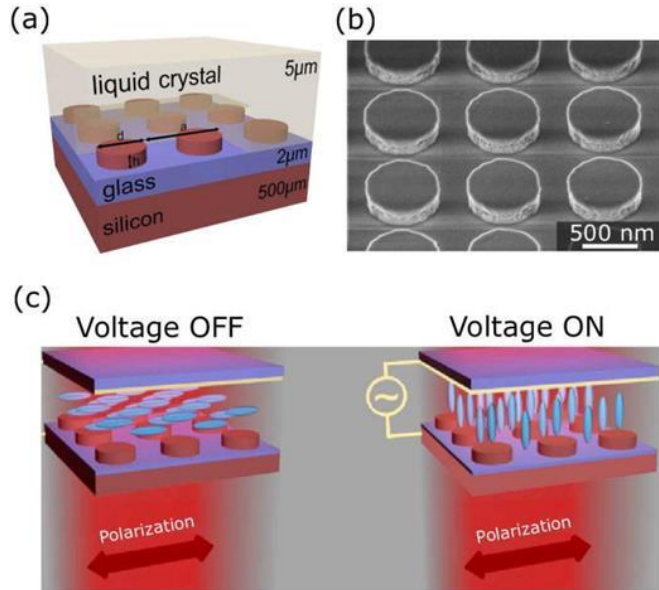


Bogaerts et al., IEEE J Sel Top Quant Electron 26, 8302517 (2020)

Programmable photonics & sustainability

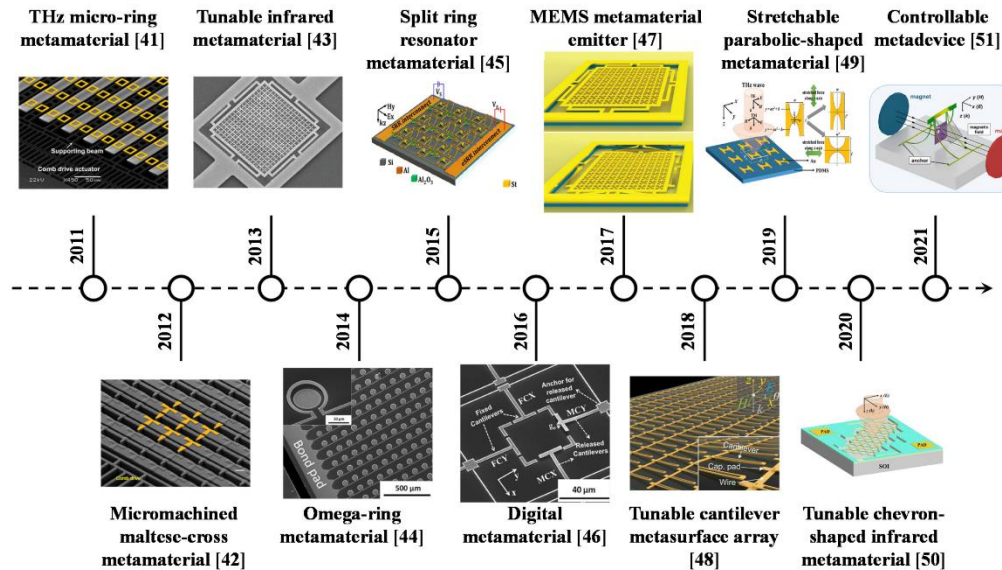
1. Switching costs energy
2. Actively maintaining a state costs energy

Liquid crystals



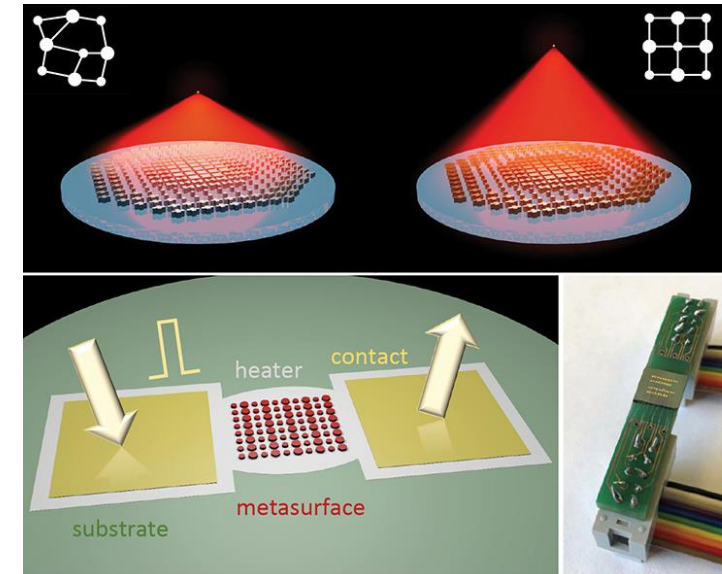
<https://doi.org/10.1063/1.4976504>

MEMS



<https://doi.org/10.3390/electronics11020243>

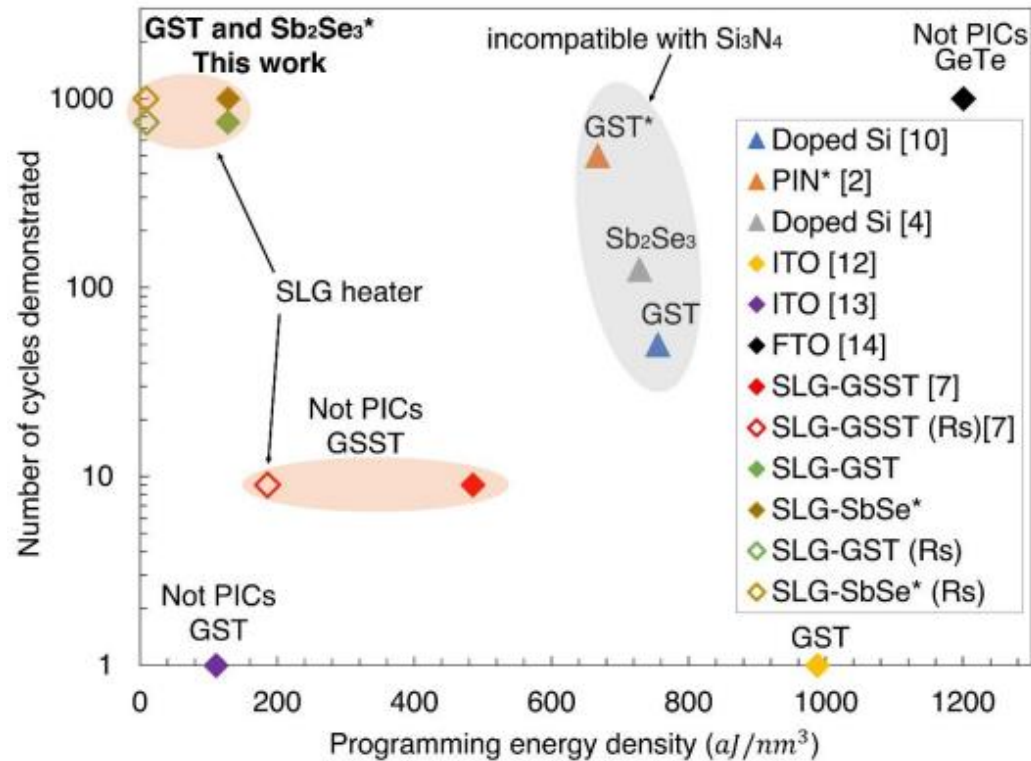
Phase change



M.Y. Shalaginov et al. Nat. Commun. 12, 1225 (2021).

Programmable photonics & sustainability

1. Switching costs energy
2. Actively maintaining a state costs energy



Fang, Z., et al. *Nat. Nanotechnol.* **17**, 842–848 (2022)

PCM switching energy:

- Typically $>100 \text{ aJ}/\text{nm}^3$
- For a metasurface of 400nm thickness this means:

Energy required:

$$E_{\text{PCM}} = 40 \text{ nJ} / \mu\text{m}^2 = 4 \text{ J}/\text{cm}^2$$

This energy is typically applied on a short time scale of 100-1000ns

$$P_{\text{peak}} = 40 \text{ mW} / \mu\text{m}^2 = 4 \text{ MW}/\text{cm}^2$$

Can be done easily

Not easy in single-shot

Programmable photonics & sustainability

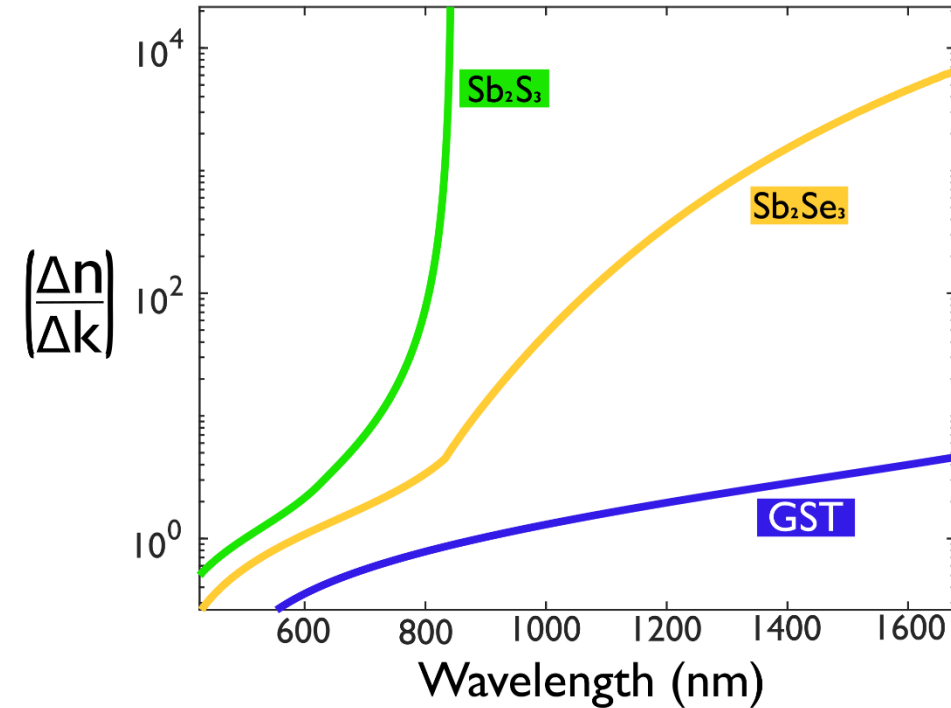
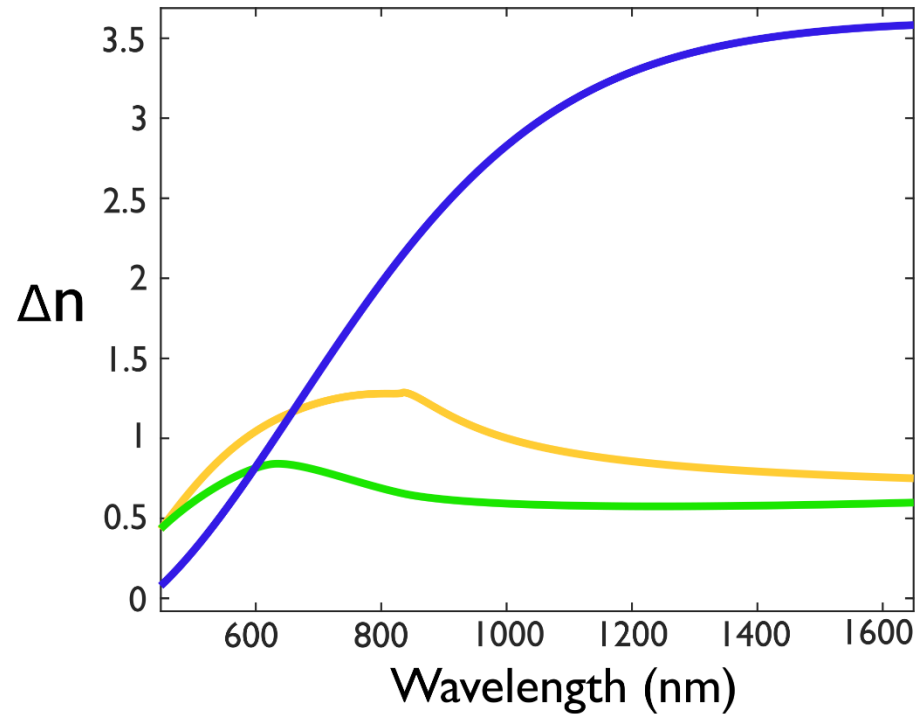
Non-volatile PCMs could be competitive for low-energy programmable photonics compared to volatile technologies:

- For applications that require a relatively low rate of changes (defined by write energy $<$ non-volatile retention energy)
- If we can demonstrate good switching of thicker (100s of nm) layers
- Sufficient durability for cycling $>10^6$ (?) cycles
- Thermal stability acceptable for the application

Fang, Z., *et al.* *Nat. Nanotechnol.* **17**, 842–848 (2022)

Optical switching using Phase change materials

- Antimonide PCMs have a higher Figure of Merit than GST

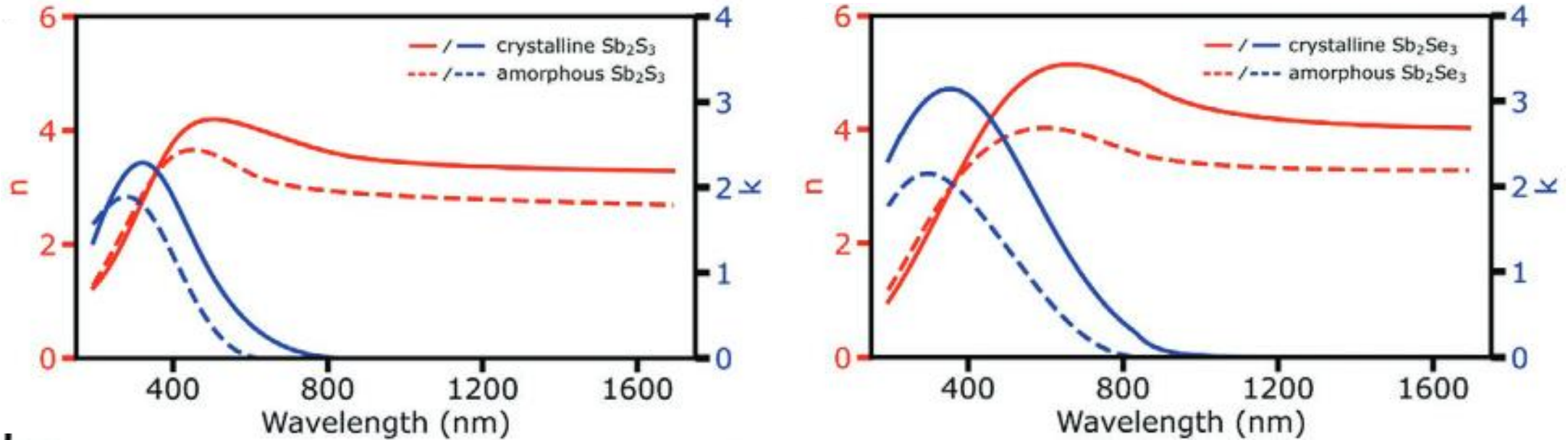


Sb_2S_3 : Dong, W., Simpson, R.E. et al. *Adv. Funct. Mater.* 29, 1806181 (2019)

Sb_2Se_3 : Delaney, M., Zeimpekis, I., Lawson, D., Hewak, D. W., Muskens, O. L., *Adv. Funct. Mater.* 2020, 30, 2002447.

Optical switching using PCMs: Ellipsometry results

- Ultralow optical losses $k < 10^{-5}$ in telecom range (1550nm)

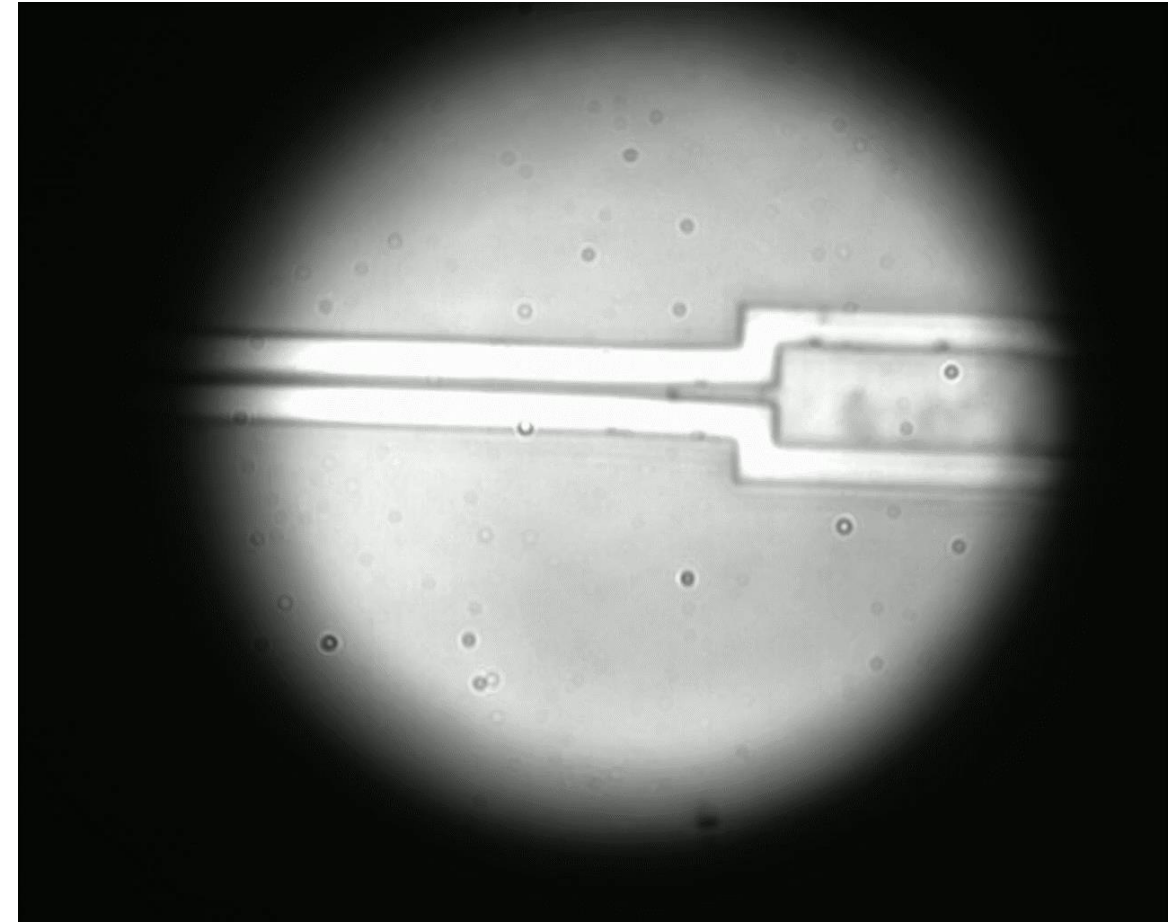


		$\lambda = 633 \text{ nm}$	$\lambda = 800 \text{ nm}$	$\lambda = 1060 \text{ nm}$	$\lambda = 1310 \text{ nm}$	$\lambda = 1550 \text{ nm}$
Sb_2S_3	Amorphous	$3.148 + 0i$	$2.943 + 0i$	$2.829 + 0i$	$2.767 + 0i$	$2.712 + 0i$
	Crystalline	$3.989 + 0.276i$	$3.630 + 0.008i$	$3.413 + 0i$	$3.343 + 0i$	$3.308 + 0i$
Sb_2Se_3	Amorphous	$4.013 + 0.532i$	$3.660 + 0.028i$	$3.372 + 0i$	$3.305 + 0i$	$3.285 + 0i$
	Crystalline	$5.132 + 1.403i$	$4.939 + 0.402i$	$4.313 + 0.010i$	$4.121 + 0.001i$	$4.050 + 0i$

Programmable silicon photonics using Sb_2Se_3

Optical switching of Multimode interference (MMI) device

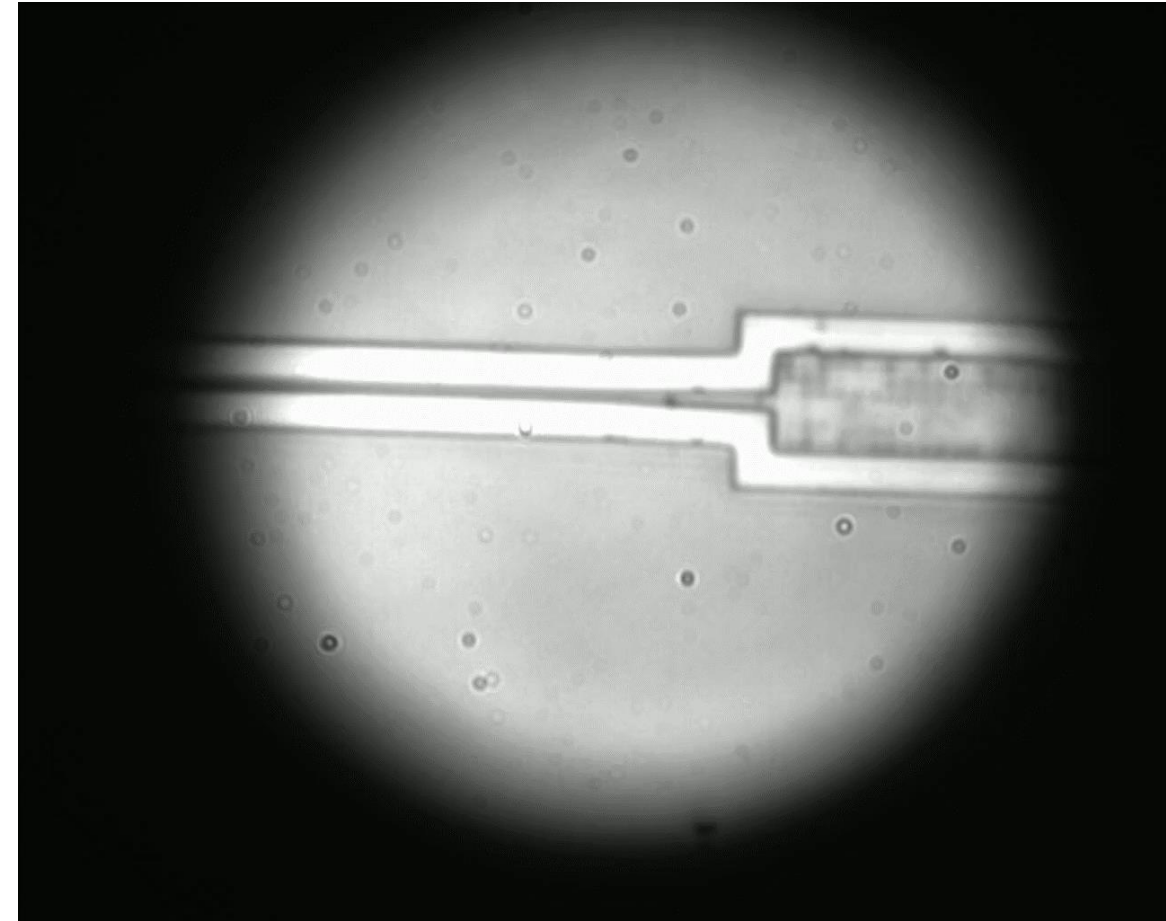
- Precise 2D control of individual pixels on a MMI was achieved
- Pixels can be set and reset in complex patterns



Programmable silicon photonics using Sb_2Se_3

Optical switching of Multimode interference (MMI) device

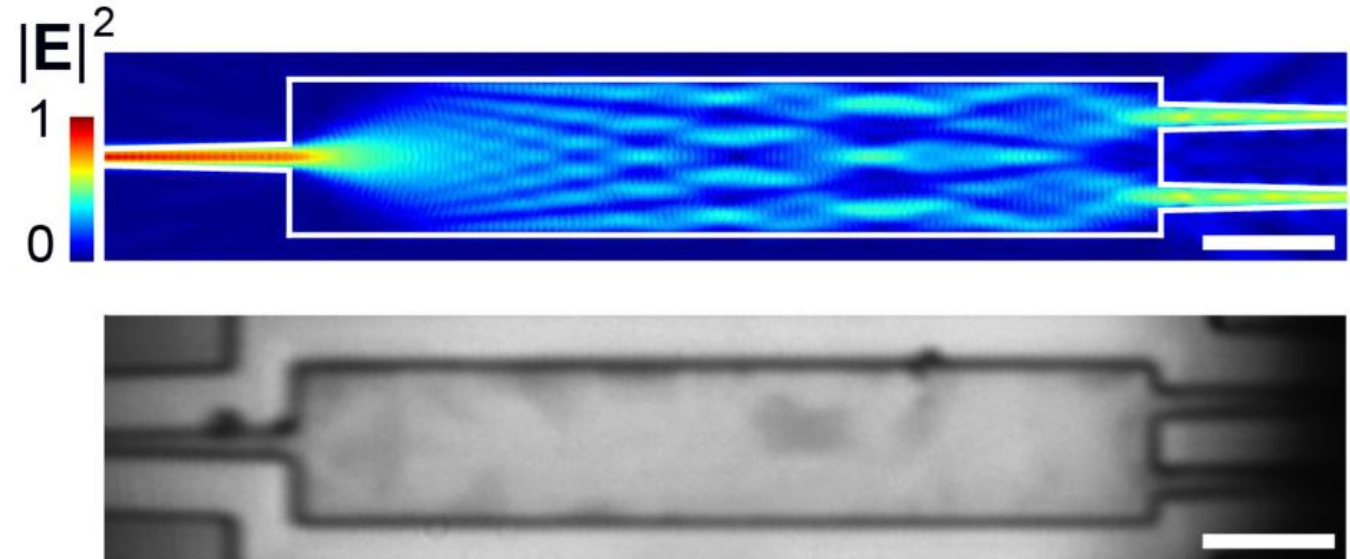
- Precise 2D control of individual pixels on a MMI was achieved
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Programmable silicon photonics using Sb_2Se_3

Optical switching of Multimode interference (MMI) device

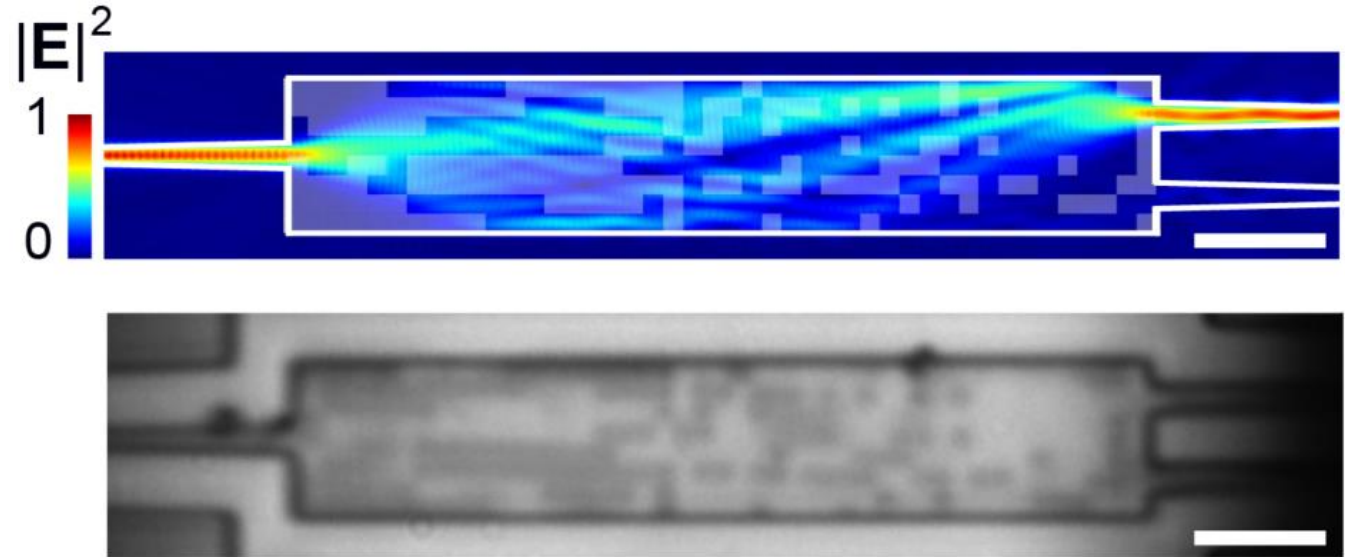
- Unperturbed device acts as a 50:50 power splitter



Programmable silicon photonics using Sb_2Se_3

Optical switching of Multimode interference (MMI) device

- Unperturbed device acts as a 50:50 power splitter
- Patterned device acts as a 92%:8% power splitter



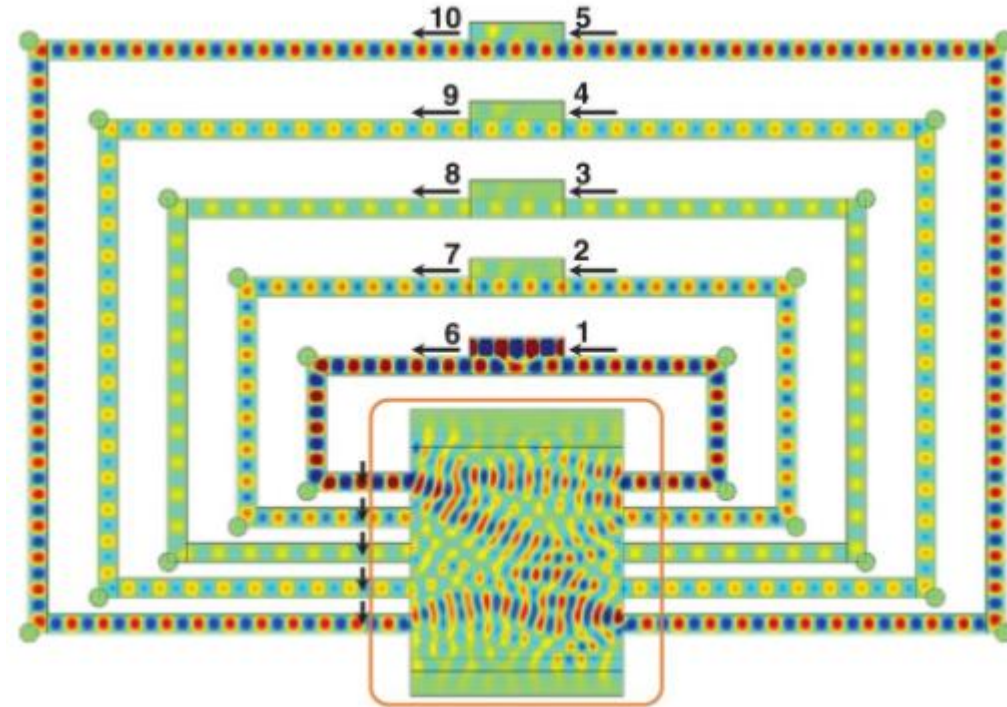
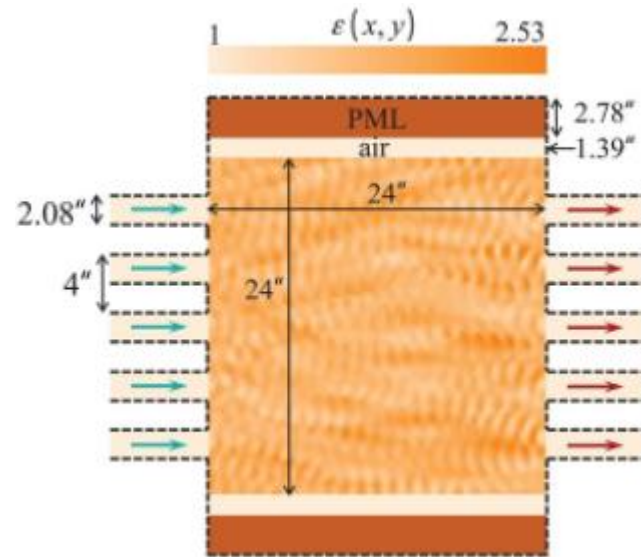
Programmable silicon photonics using Sb_2Se_3

Is it a metamaterial?

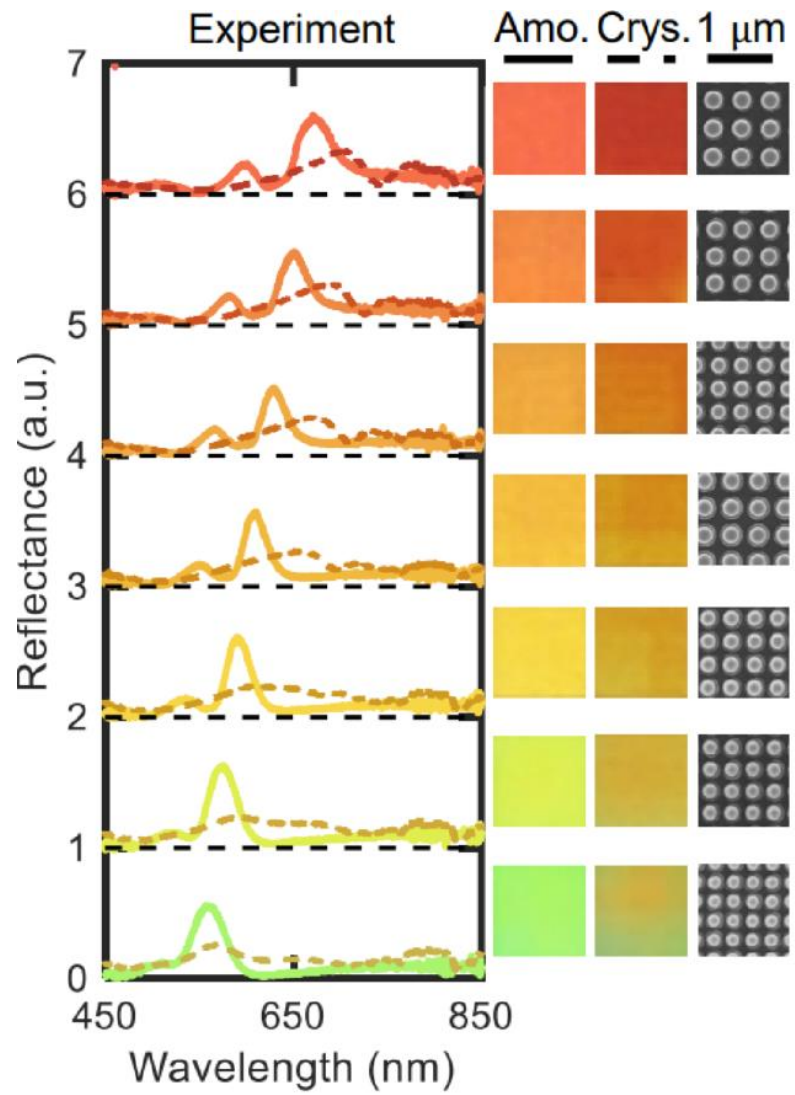
Inverse-designed metastructures that solve equations

[NASIM MOHAMMADI ESTAKHRI](#) , [BRIAN EDWARDS](#) , AND [NADER ENGHETA](#)  [Authors Info & Affiliations](#)

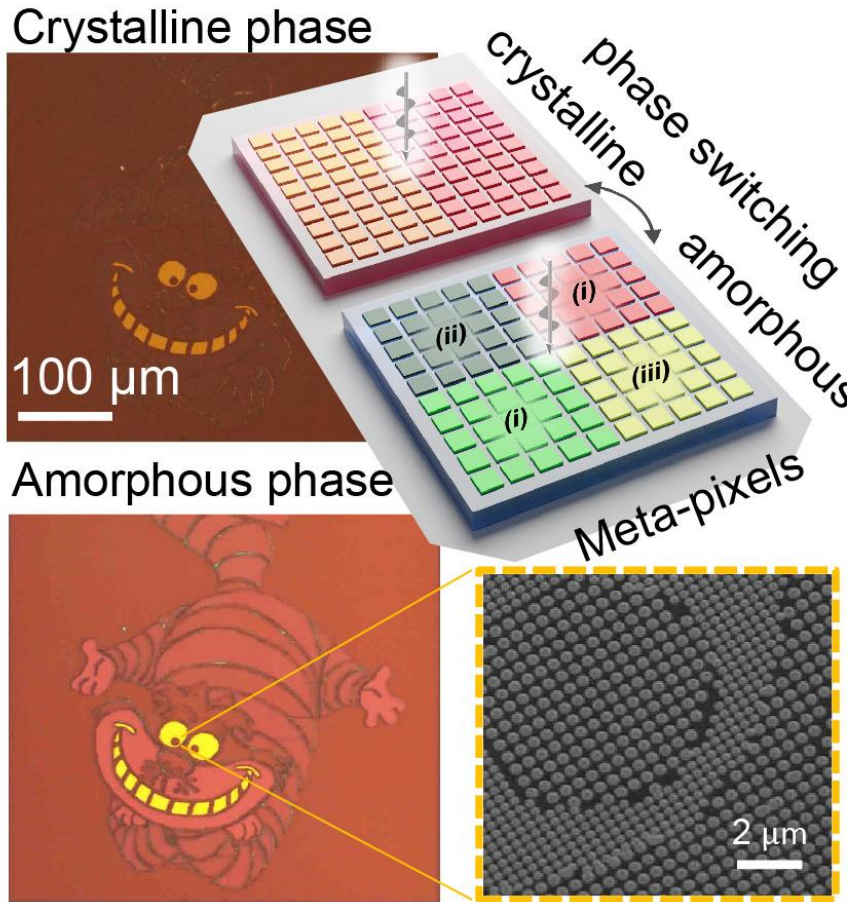
SCIENCE · 22 Mar 2019 · Vol 363, Issue 6433 · pp. 1333-1338 · DOI: 10.1126/science.aaw2498



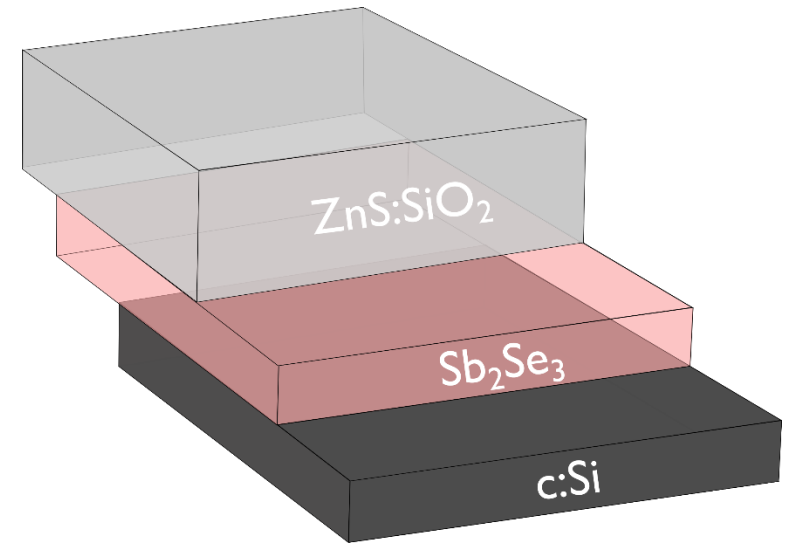
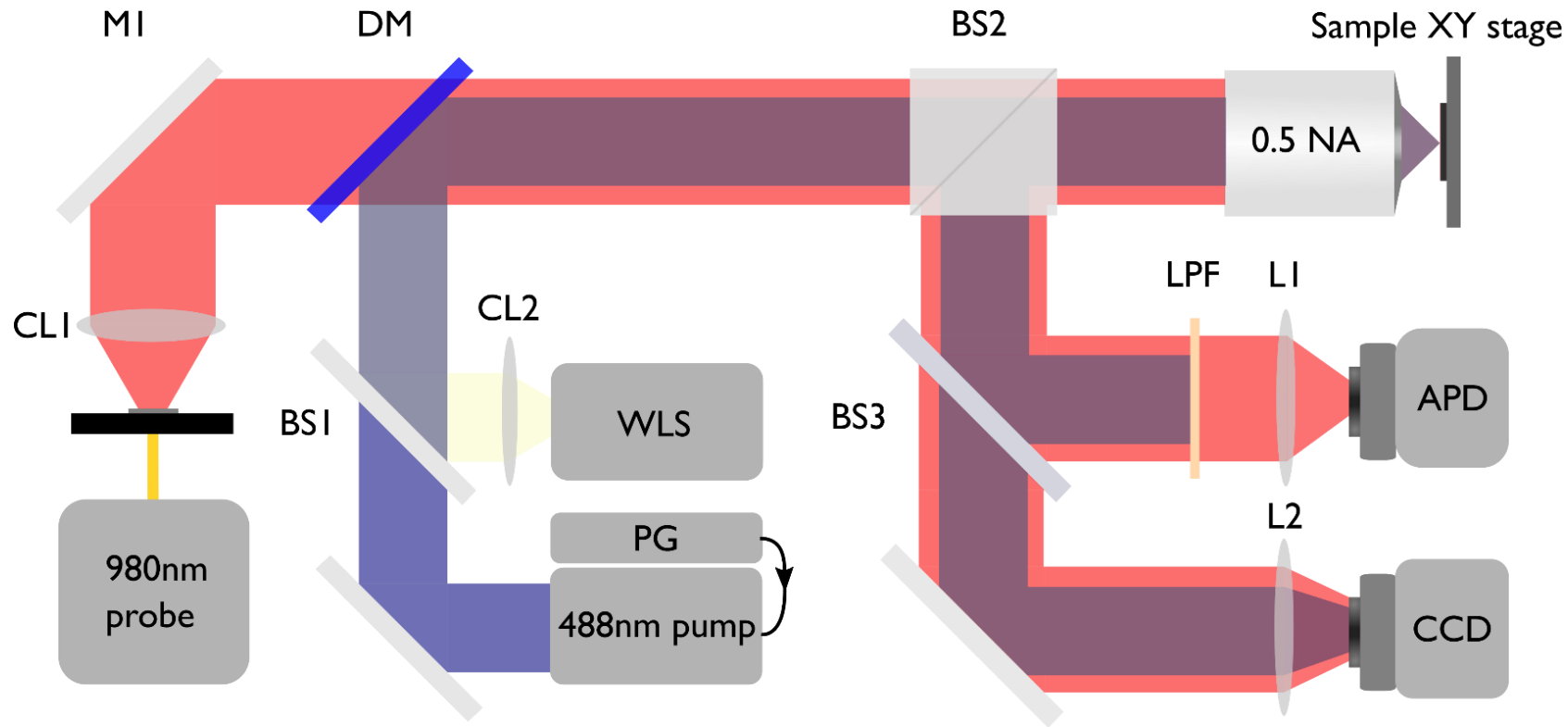
Programmable metasurface structural color using Sb-based PCMs



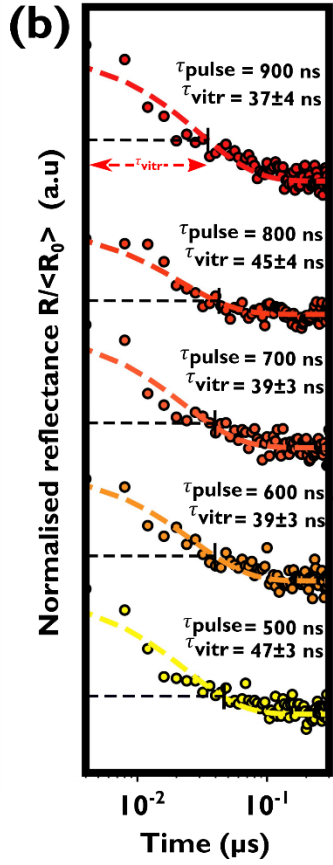
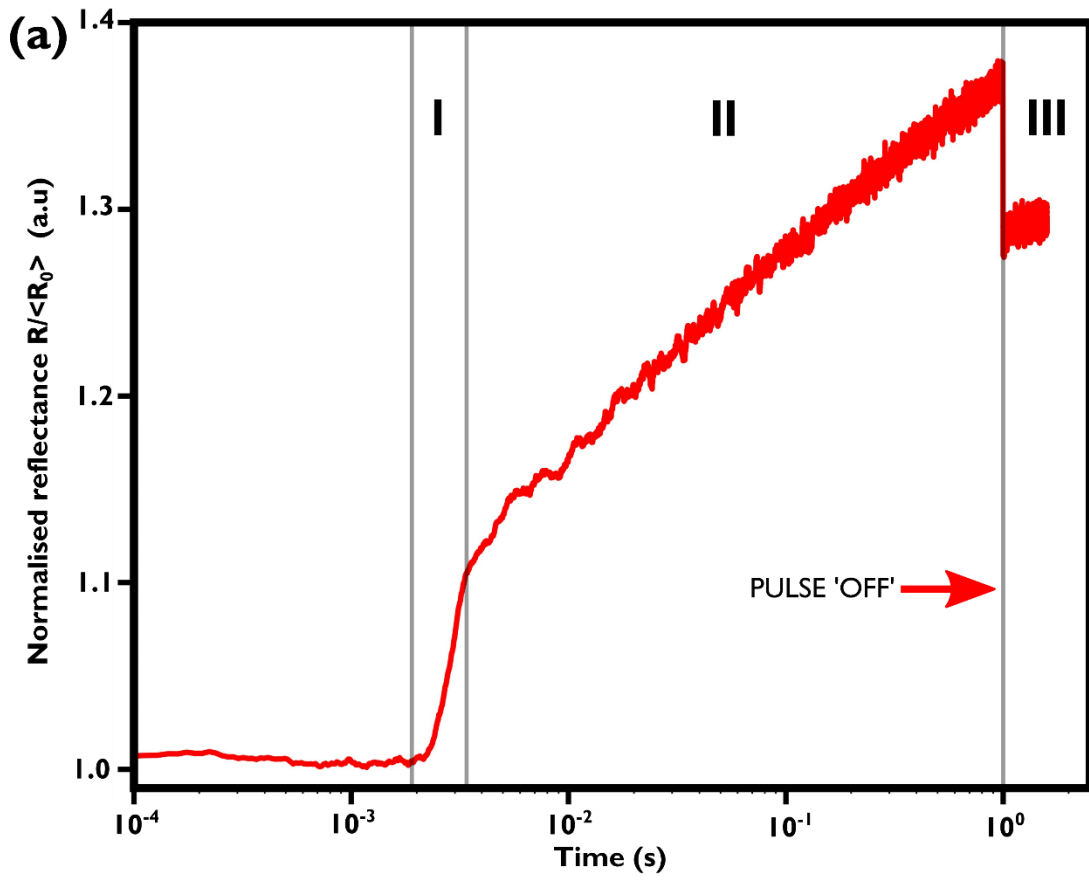
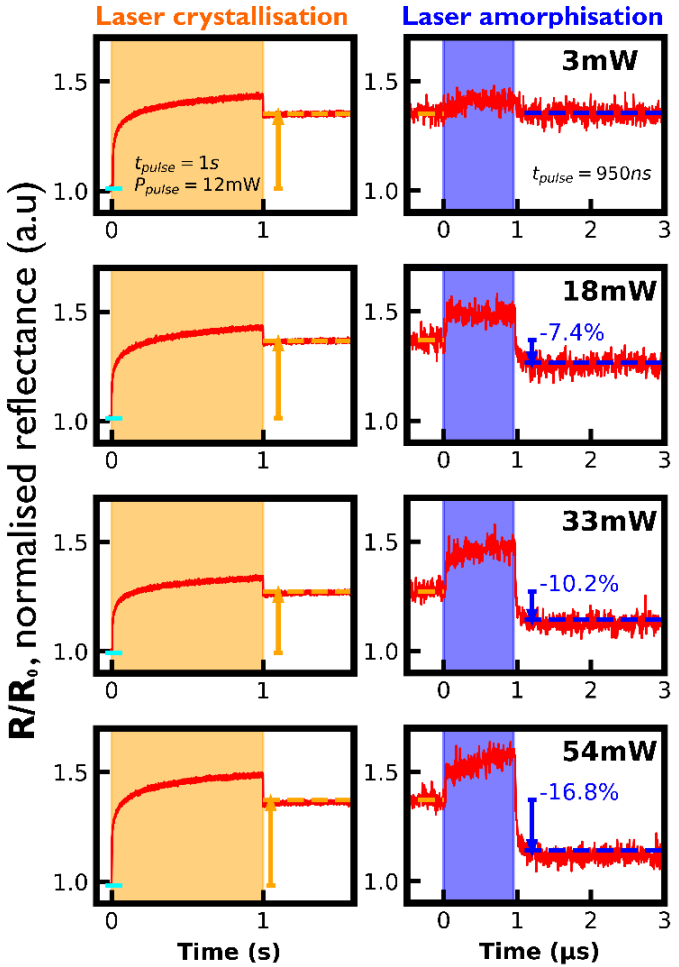
Ali Abidi Group, Georgia Tech.



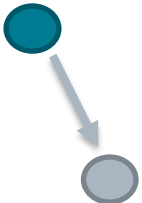
Probing the phase transitions in Sb_2Se_3



Time-resolved optical switching measurements of 20nm Sb_2Se_3



Switching of thicker Sb_2Se_3 layers



Amorphisation pulse
Pulse length: 10 ns – 100 μs
Pulse power: 4 mW – 60 mW

Aim: Sweep pulse parameters to establish window for reversible switching



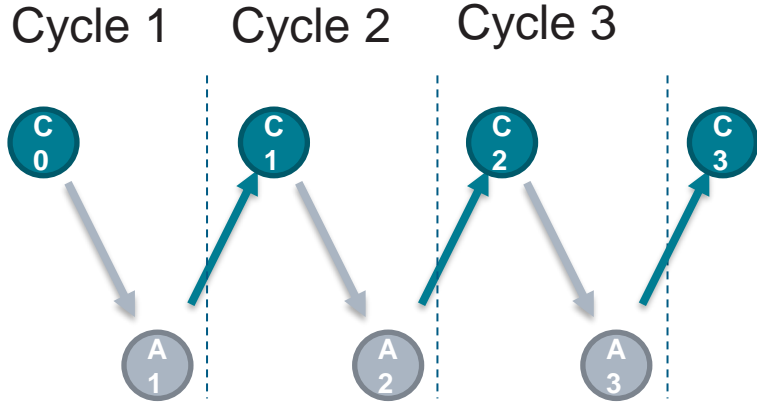
Crystallisation pulse
Pulse length: 1 second
Pulse power: 1mW

Aim: Reset to crystalline state without causing damage

Three Cycles per pixel

Crystalline

Amorphous

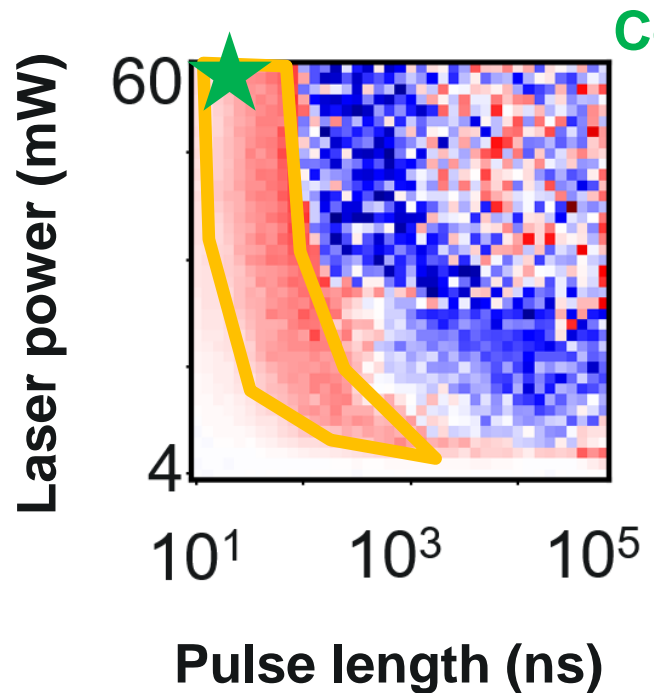


Aim: Identify the initial burn-in and instantaneous damage effects from lack of cyclability

Switching of thicker Sb_2Se_3 layers

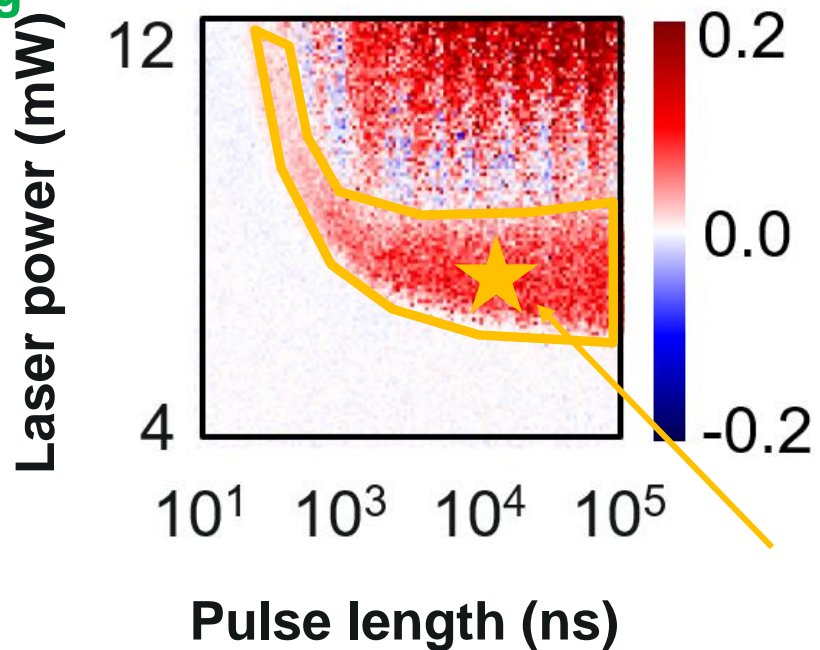
Sb_2Se_3 thickness 400nm

Amorphization map

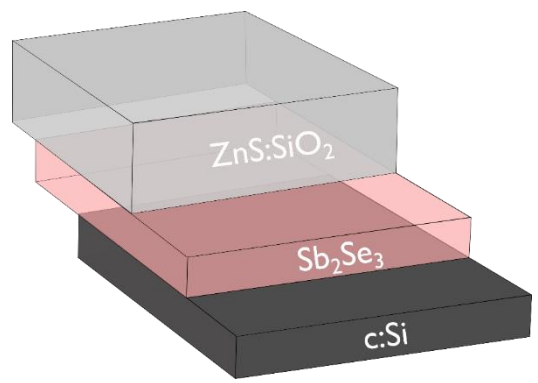


Constant setting
 $P_{\text{amo}} = 60 \text{ mW}$
 $T_{\text{amo}} = 50 \text{ ns}$

Crystallization map

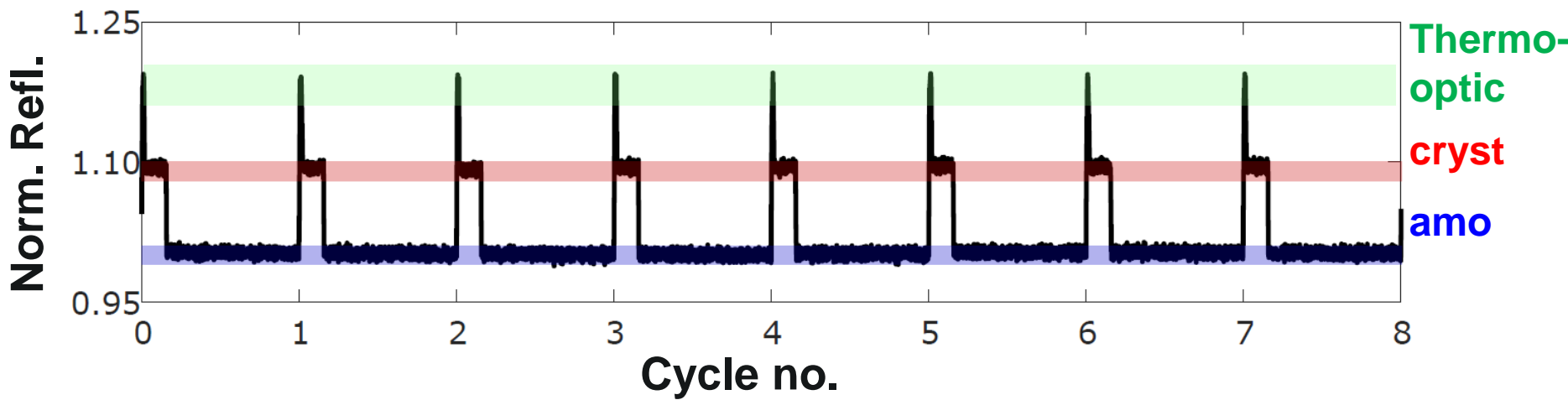
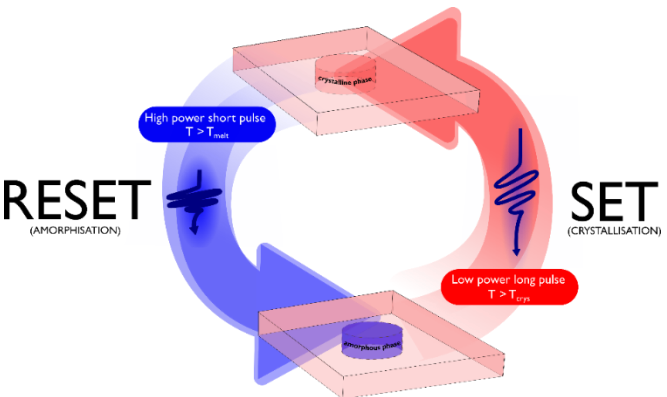


80 nm Sb_2Se_3
170 nm $\text{ZnS}:\text{SiO}_2$

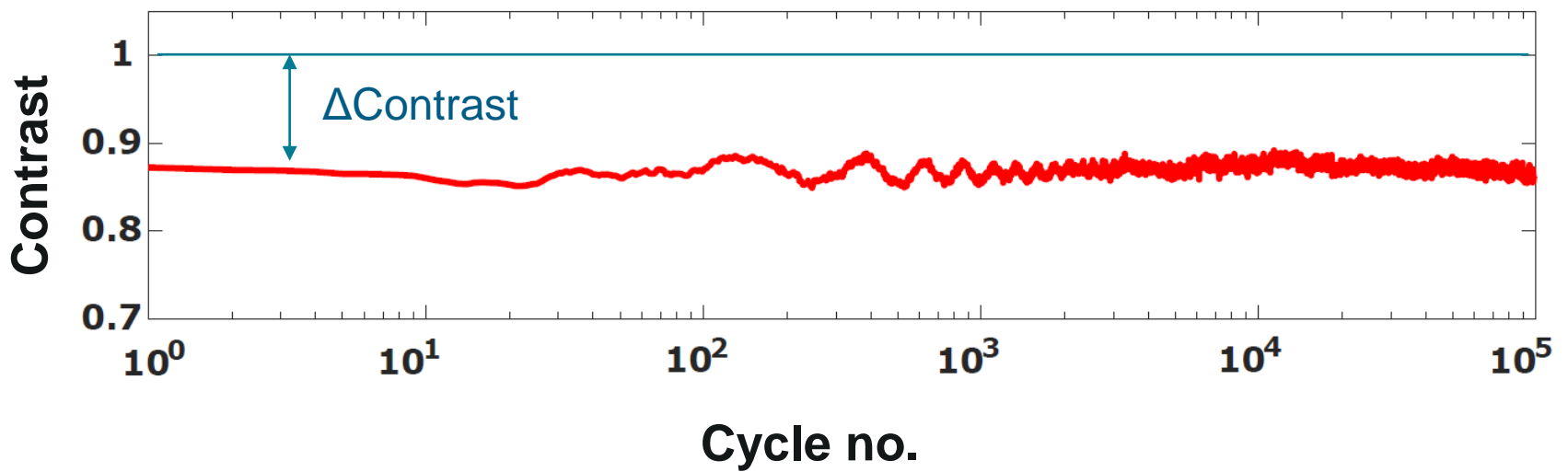


Selected crystallization
'Sweet spot'
 $P_{\text{cry}} = 6 \text{ mW}$, $T_{\text{cry}} = 12 \mu\text{s}$

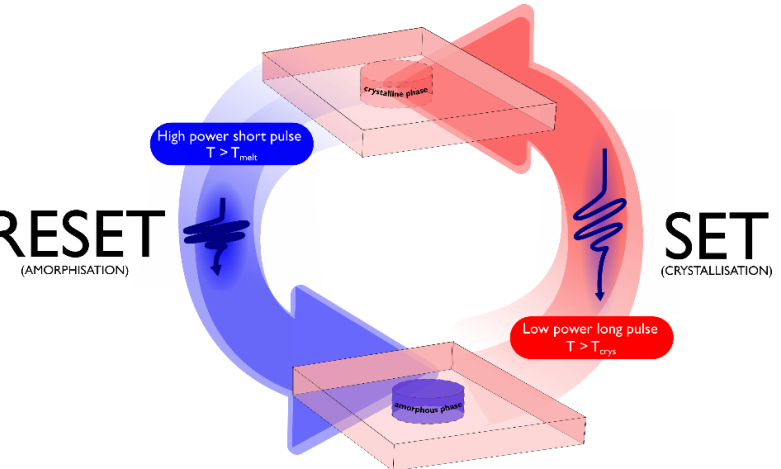
Cycling at 1KHz – 400nm thick Sb_2Se_3 layer



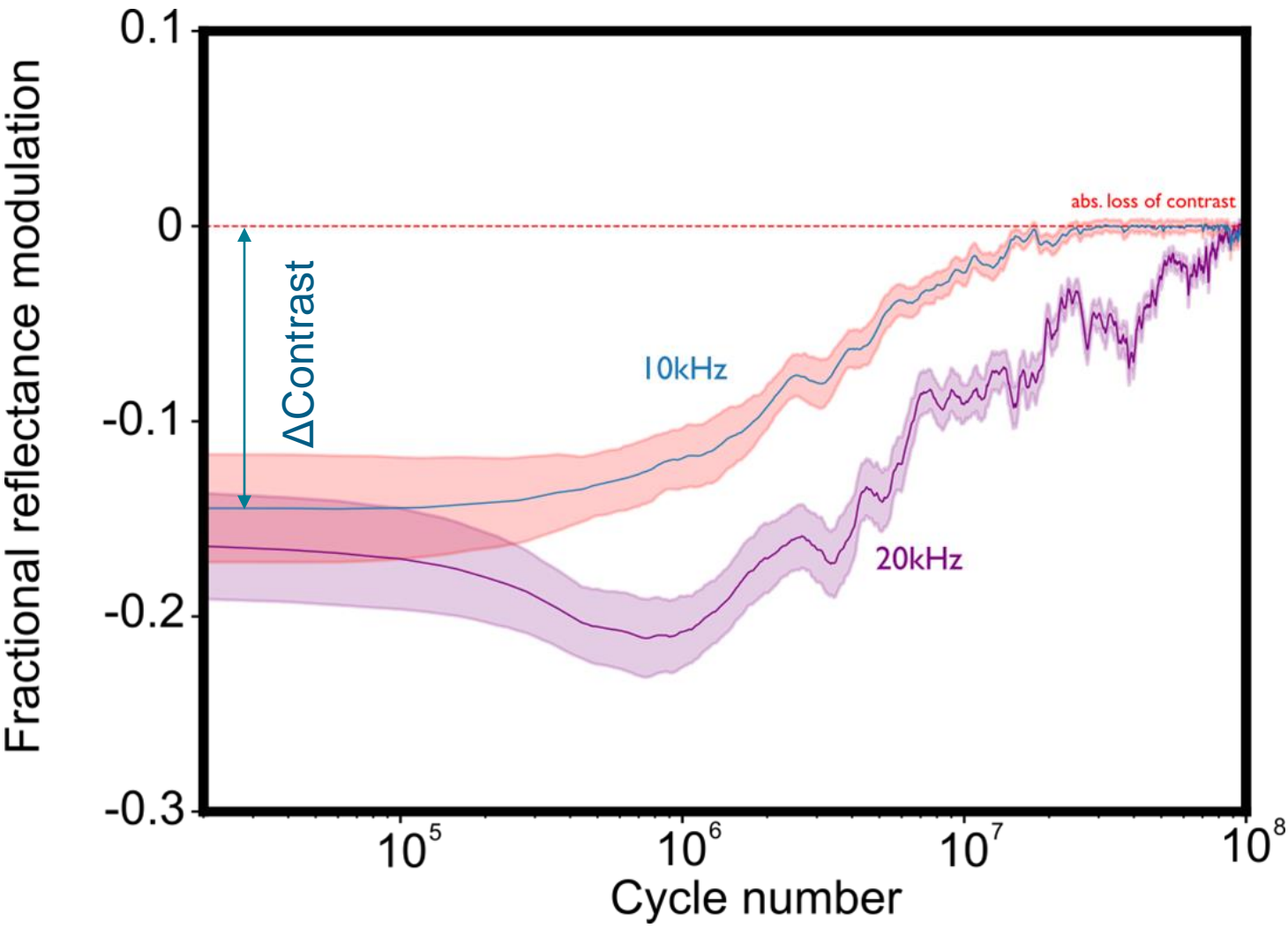
- 1 Crystallisation pulse:**
6mW, 12 μ s
- 2 Amorphisation pulse:**
60mW, 50ns



Driving at 10KHz – faster crystallisation of laser-written glass regions



Around 10^6 cycles reversible switching demonstrated for Sb_2Se_3



Conclusions

- Introduced Sb_2Se_3 as new optical PCM
- Demonstration of programmable photonics using Sb_2Se_3
- Optical switching of thick (400nm) Sb_2Se_3 films with $>10^6$ cycles

Delaney et al., Adv. Funct. Mater. 2002447 (2020)

Delaney et al., Science Adv 7, eabg3500 (2021)

Lawson et al., J. Opt. 24, 064013 (2022)

